Role of spin mixing conductance in determining thermal spin pumping near the ferromagnetic phase transition in EuO_{1-x} and La_2NiMnO_6

Kingshuk Mallick,¹ Aditya A. Wagh,¹ Adrian Ionescu,² Crispin H. W. Barnes,² and P. S. Anil Kumar^{1,*}

¹Physics Department, Indian Institute of Science, Bangalore - 560012, India

²Cavendish Laboratory, Physics Department, University of Cambridge, Cambridge CB3 0HE, United Kingdom

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We present a comprehensive study of the temperature (*T*) dependence of the longitudinal spin Seebeck effect (LSSE) in Pt/EuO_{1-x} and Pt/La₂NiMnO₆ (LNMO) hybrid structures across their Curie temperatures (*T_c*). Both systems host *ferromagnetic* interaction below *T_c*, and hence present optimal conditions for testing magnon spin current based theories against *ferrimagnetic* yttrium iron garnet. Notably, we observe an anomalous Nernst effect generated voltage in bare EuO_{1-x}, however, we find LSSE predominates the thermal signals in the bilayers with Pt. The *T* dependence of the LSSE in small *T* range near *T_c* could be fitted to a power law of the form $(T_c - T)^p$. The derived critical exponent *P* was verified for different methods of LSSE representation and sample crystallinity. The results are explained based on the magnon-driven thermal spin pumping mechanism that relates the *T* dependence of LSSE to the spin mixing conductance (*G_{mix}*) at the heavy metal/ferromagnet interface, which in turn is known to vary in accordance with the square of the spontaneous magnetization (*M_s*). Additionally, the *T* dependence of the real part of *G_{mix}* derived from spin Hall magnetoresistance measurements at different temperatures for the Pt/LNMO structure further establishes the interdependence.

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I. INTRODUCTION

The discovery of spin Seebeck effect (SSE) in 2008 by Uchida et al. [1] opened up the multidisciplinary field of spin caloritronics, combining thermoelectricity and spintronics [2,3]. In the longitudinal SSE (LSSE) configuration an out-of-plane temperature gradient generates a spin current in a magnetic material which can be detected via the inverse spin Hall effect (ISHE) in an adjoining heavy metal (HM) layer, like Pt and W [4,5]. Another related phenomenon observed in a ferromagnetic insulator (FI)/HM bilayer is the change in HM resistance depending on the magnetization orientation of the FI layer. A charge current passing through the HM layer can generate a spin current via the spin Hall effect which gets absorbed or reflected from the FI layer depending on the magnetization direction. This modifies the resistance in the HM layer and this phenomenon is commonly referred to as spin Hall magnetoresistance (SMR) [6,7]. SMR has proven to be a successful approach to quantify the spin mixing interfacial conductance (G_{mix}) of FI/NM bilayers [8–11], an important parameter affecting both SMR and LSSE [12-14].

Temperature variation of the LSSE signal has been carried out for investigating various thermospin properties such as phonon-mediated effects [15–19], correlation between LSSE and magnon excitation [20–23], effects of metal-insulator transition [24,25], and recently, antiferromagnetic phase transitions [26–33]. The low-temperature evolution of LSSE in the prototypical yttrium iron garnet (YIG)/Pt bilayer far from T_c can be understood based on the magnon spin current theory [20]. However, when it comes to the temperature de-

pendence near T_c , theoretical predictions and experimental evidences have failed to come to a consensus. Uchida *et al.* [34] observed a rapid decrease of LSSE signal (V_{LSSE}) with an increase in temperature in YIG/Pt, i.e., $V_{\text{LSSE}} \propto (T_c - T)^3$. Measurements on thick films of YIG/Pt by Wang *et al.* [14] obtained $V_{\text{LSSE}} \propto (T_c - T)^{1.5}$. Other than YIG, LSSE(T)for two other manganites namely, La_{0.7}Sr_{0.3}MnO₃ [35] and La_{0.7}Ca_{0.3}MnO₃ [25], could be described by $(T_c - T)^{1.9}$ and $(T_c - T)^{0.7}$ respectively. On the theoretical side, according to the magnon-driven thermal spin pumping mechanism, the LSSE voltage is predominantly determined by G_{mix} [12,20,36] which Ohnuma et al. [37] predicted to follow $G_{\rm mix} \propto (4\pi M_s)^2$ near T_c . This implies the change in $G_{\rm mix}$ is closely associated with the T-dependent magnetic ordering in the sample. Combining these arguments it is expected that LSSE $\propto M_s^2$, where M_s is the saturation magnetization. Consequently, if *P* and β are the critical exponents of LSSE and M_s respectively, then, $P = 2\beta$. However, some authors have also presented a different perspective based on numerical and analytical investigations [38,39] which suggest that the LSSE should vary in accordance with the magnetization. Therefore, both should share the same critical exponents. To address these discrepancies from an experimental standpoint, we investigate T evolution of LSSE in EuO_{1-x} and La₂NiMnO₆ across their ferromagnet to paramagnet transition temperatures (T_c) .

EuO has a rocksalt structure (a = 0.5144 nm) [40] whose large ferromagnetic response, below its curie temperature of 69 K, is due to the half-filled 4*f* Eu²⁺ orbital [41–43]. Oxygen deficient EuO, i.e., EuO_{1-x}, is intrinsically electron doped which undergoes simultaneous ferromagnetic and insulating-conducting phase transition across which the resistivity can drop by 13 orders of magnitude [44,45] and the

^{*}anil@iisc.ac.in

conduction electrons become nearly 100% spin polarized [46,47]. Electron doping can also enhance the T_c above 140 K [48]. These properties and the close lattice matching with Si makes EuO_{1-x} an excellent candidate for spintronic applications [47,49]. EuO has also been predicted to be the ideal candidate to test theories on spin transport across FM/HM bilayers [38].

La₂NiMnO₆ (LNMO) is a double perovskite ferromagnetic insulator which has a Curie temperature close to room temperature ($T_c = 280$ K) [50]. Its ferromagnetism arises from 180° Ni²⁺-O-Mn⁴⁺ superexchange bonding between an empty Mn^{4+} e_g orbital and a half-filled d orbital of the neighboring Ni^{2+} site [51,52]. It is considered to be a promising candidate for spintronics [53-55]. Recently, a spin pumping study from LNMO into Pt by Shiomi and Saitoh [54] demonstrated spin transport not only in the ferromagnetic state of LNMO but also in a wide temperature range above T_c . This was attributed to short-range ferromagnetic correlations that exist in LNMO above T_c [56,57]. They also present LSSE results in a small temperature range near T_c which is shown to vary in accordance with the magnetization M(T). In this paper, we undertake exhaustive T-dependent LSSE measurements on both epitaxial and polcrystalline LNMO films, wherein we focus on the power-law decay of the LSSE signal near T_c . Good control of interface quality and optimized measurement conditions ensure a higher signal-to-noise ratio down to the smallest signal close to T_c , thereby allowing direct correlation with G_{mix} obtained from SMR measurements on polycrystalline films. To establish the generality of the observed power-law behavior, T-dependent LSSE was measured for a polycrystalline Pt/EuO_{1-x} structure as well. Interestingly, we observe an anomalous Nernst effect (ANE) signal in EuO_{1-x} without the top Pt. After separating the ANE voltages from the total signal we find that LSSE dominates the electrical signals in Pt/EuO_{1-x} . We discuss our results based on the magnon-driven thermal spin pumping mechanism that relate the T evolution of LSSE to G_{mix} .

II. EXPERIMENT

Epitaxial and polycrystalline LNMO films having thicknesses of 57 and 28 nm were grown at 800 °C and 0.6 mbar O_2 pressure by pulse laser deposition (PLD) on SrTiO₃ (STO)(001) and Au buffered gadolinium gallium garnet (GGG)(111) substrates respectively. Polycrystalline targets were ablated using a KrF laser source with $\lambda = 248$ nm at a repetition rate of 5 Hz. Postdeposition, the films were annealed in situ in 500 mbar O2 pressure at 600 °C for 1 h and subsequently cooled down to room temperature at $5 \,^{\circ}C/min$. For LSSE and SMR measurements, Pt was deposited on top of LNMO using a standard e-beam evaporation technique. The surface was cleaned with in situ annealing and argon plasma before Pt deposition. The nominal sample structure was STO(001)/LNMO(57 nm)/Pt(4.5 nm) (henceforth sample A) and GGG(111)/Au(5 nm)/LNMO(57 nm)/Pt(5 nm) (henceforth sample B).

The polycrystalline EuO_{1-x} sample was deposited at room temperature using a CEVP rf/DC magnetron sputtering system with a base pressure of 5×10^{-9} Torr. Codeposition was performed using two targets: a 99.99% pure Eu₂O₃ and a



FIG. 1. (a),(c) HR-XRD of the epitaxial LNMO/STO and polycrystalline Pt/EuO/Pt/Si sample respectively. Inset of (a) shows the presence of clear Laue oscillations on either side of the substrate peak. Panels (b) and (d) represent the final device configuration for LSSE measurements.

99.99% pure Eu target. The EuO_{1-x} film was codeposited while maintaining the rf power constant at 50 W for the Eu₂O₃ target and the DC deposition current for the Eu target at 0.15 A. The growth was performed in an Ar^+ plasma at a pressure of 2 mTorr with a flow rate of 14 SCCM (SCCM denotes cubic centimeter per minute at STP). The substrates used were one inch Si (001) with a native oxide layer. One Pt layer was deposited between the substrate and the EuO_{1-x} film and another one on the top at 2 mTorr, with 0.1-A DC current and at 14 SCCM Ar flow. The nominal sample structure, $Si(001)/SiO_2(1.4 \text{ nm})/Pt(5 \text{ nm})/EuO_{1-x}(97 \text{ nm})/Pt(5 \text{ nm}),$ is shown in Fig. 1(d). The top Pt layer serves as the ISHE detection layer and also protects the EuO_{1-x} from atmospheric degradation. The Pt seed layer was necessary in order to avoid intermixing at the Si/SiO₂/EuO_{1-x} interface, which otherwise has resulted in poor EuO_{1-x} films with large roughness.

The crystal structure of the films was evaluated by highresolution x-ray diffraction (HRXRD) using Cu- $K\alpha$ radiation. A sample magnetic moment was recorded as a function of field and temperature using superconducting quantum interference device (SQUID) magnetometry. Figure 1(a) is the HR-XRD scan on a LNMO(28 nm)/STO sample around the (001)_{STO} reflections. The pseudocubic pervoskite bulk lattice parameter of LNMO is 3.879 Å [58] which is very close to that of STO (=3.905 Å), hence the LNMO peak appears as humps on the STO peaks. This indicates LNMO films were grown epitaxially which was confirmed from clear Laue fringes around the (002) reflection indicating high crystallinity, flat surface, and homogeneity of the grown film [see inset of Fig. 1(a)]. In contrast, the EuO_{1-r} on Si (001) has a preferred (001) orientation, as seen in Fig. 1(c) and is polycrystalline confirmed from the large full width at half maximum of the (002) peak and its omega scan (not shown).

The magnetic properties of LNMO thin films including its T_c (ferromagnetic to paramagnetic transition) and



FIG. 2. (a),(b) Field-cooled *M*-*T* curves of the LNMO/STO and Pt/EuO/Pt/Si sample respectively. Applied in-plane magnetic fields strengths are also denoted. Insets of both figures show presence of minima in the dM/dT curves, depicting the position of T_c . (c),(d) Isothermal *M*-*H* hysteresis curves with field applied in plane for LNMO/STO and Pt/EuO/Pt/Si sample respectively. Inset of (c) shows in detail the low-field region.

saturation magnetization (M_s) has been found to vary from its bulk $(T_c^{bulk} = 270 \text{ K}, M_s^{bulk} \text{ at } 0 \text{ K} = 5 \mu_B/\text{f.u.})$ influenced by the growth conditions, film thickness, and stoichiometry [58–60]. The field-cooled magnetization (M) vs T measured at 100 Oe and its derivative is shown in Fig. 2(a) and its inset. From the minima in the derivative, we estimate the $T_c = 241 \text{ K}$. *M*-*H* loops at T = 10 K [Fig. 2(c)] exhibit expected hysteretic behavior with a coercive field and M_s of about 300 Oe and 3.5 $\mu_B/\text{f.u.}$ respectively. From field-cooled *M*-*T* of LNMO/Au/GGG (see the Appendix) the T_c was found identical to LNMO/STO, 241 K.

EuO is regarded as a model Heisenberg ferromagnet with M_s at 0 K = 7 μ_B /f.u. and T_c = 69 K [41–43]. The increase in T_c of EuO_{1-x} depends on the extent of electron doping due to O_2 vacancies [48,61]. The presence of these defects create spin polarized states near the Fermi energy thus modifying the density of states and supplying electrons to the conduction band. The T_c can be enhanced due to conductionelectron-mediated Ruderman-Kittel-Kasuya-Yosida (RKKY) coupling between the Eu 4f spins [62]. Hence a field-cooled *M*-*T* for the EuO_{1-x} resembles a system having two domes, as observed for our EuO_{1-x} films [Fig. 2(b)] [48,63]. The obtained low-temperature feature at 65 K (T_{EuO}) is close to the bulk value of 69 K and another minimum at 144 K (T_P) of the dM/dT curve shown in the inset is the extended T_c due to RKKY interaction. *M*-*H* hysteresis loops of EuO_{1-x} [Fig. 2(d)] is characteristic of a soft ferromagnetic film having $M_s = 4.6 \,\mu_B/\text{Eu}$ and coercivity less than 80 Oe at 10 K. The deviation of M_s from the expected value for a stoichiometric EuO can be due to the extent of doping, presence of defects, or formation of traces of Eu₂O₃ upon air exposure.

The final sample stack and configuration for LSSE experiments is shown in Figs. 1(b) and 1(d). Wire bonding contact was given on the longer edge of the sample to measure the ISHE voltages using a Keithley 2182A nanovoltmeter [4]. LSSE measurements were conducted at different temperature in a modified closed cycle cryostat. To establish a temperature gradient a Cr/Au heater patterned on a sapphire substrate was placed on top of the sample with GE varnish and a constant small power was applied. This resulted in a perpendicularto-plane temperature gradient which induced thermal spin currents in the ferromagnetic layer. A constant magnetic field of magnitude 2.5 kOe was rotated in plane and the change in the generated ISHE voltage was recorded as a function of in-plane angle α ,

$$V_{\rm ISHE} = \rho_N \theta_{\rm SHE} \mathbf{J}_{\mathbf{s}} \times \sigma \tag{1}$$

where θ_{SHE} is the spin Hall angle and ρ_N is the electrical resistivity of the NM layer. The applied field was greater than the anisotropies hence V_{ISHE} has a sinusoidal variation as depicted in Figs. 3(a) and 5(a) for 50 and 25 K respectively. Similar loops were recorded at different temperature and fitted with a sine function to extract the amplitude [marked with double sided arrow in Fig. 3(a)]. Field-sweep measurements at $\alpha = 90$ have also been carried out at some temperatures which show a hysteretic variation of V_{ISHE} [Figs. 3(b) and 5(c)], resembling *M*-*H* traces. To analyze the temperature dependence of the generated signal it is important to scale the amplitude either with the temperature gradient ΔT (in units of K) or with the heat flux j_Q (in units of W/m²). j_Q can be calculated knowing the applied power and the dimension of the top heater. To acquire ΔT , standard Pt thermometry was followed, wherein the Pt resistance is initially calibrated as a function of base temperature which is later utilized to estimate the increase in temperature at the sample surface upon applying a heat flux. Initial studies reported the signal as the spin Seebeck coefficient (SSC), where SSC = $V_{\text{ISHE}}/(\Delta T \times L)$ (in units of V/Km), with L being the distance between the contacts. However, recently it has become more common to report LSSE as the spin Seebeck resistivity (SSR), where $SSR = V_{ISHE}/(j_Q \times L)$ (in units of V m/W), highlighting the associated errors in the accurate determination of the temperature gradients [64,65]. We report our findings as both SSC and SSR to test the effect of scaling in LSSE analysis. The base temperature was taken from the cryostat's diode sensor reading kept next to the sample.

III. LSSE RESULTS ON LNMO

First, the two probe resistivity of the LNMO/STO was measured, which was found to be four orders of magnitude larger than that of Pt near T_c [Figs. 3(c) and 3(d)] and demonstrated insulating behavior with temperature. Hence, ANE contributions could be neglected [24]. The heating power was chosen such that it maintains linearity of the V_{ISHE} signal as a function of ΔT and power [see inset of Fig. 3(e) for 50-K data]. For a heater of dimension 5 mm × 3.2 mm just covering the sample and a distance of 3.7 mm between voltage



FIG. 3. (a) Variation of V_{ISHE} with in-plane angle α at 50 K and subsequent fit to a sine function to determine the amplitude, denoted by an arrow. (b) Hysteretic switching of V_{ISHE} as function of in-plane field applied along $\alpha = 0$ at 175 K. (c),(d) resistivity as a function of temperature for Pt and LNMO layer respectively, (e) LSSE amplitudes represented as SSC (open triangles) and SSR (open circles) at different temperature and power law fitting near T_c . Insets show linear relation between generated voltage, temperature gradient and applied power.

probes [see Fig. 1(b)], we show the T evolution of both SSC and SSR for sample A in Fig. 3(e). The signal appears only below T_c (=241 K) and then keeps increasing with decrease in temperature till 180 K. The SSR at 200 K is 1.3×10^{-8} in V m/W which is comparable to the value of 2×10^{-8} V m/W at 200 K for Pt(6 nm)/YIG(40 nm) reported by Prakash et al. [65]. In the only other report of LSSE for Pt/LNMO, Shiomi and Saitoh [54] show LSSE variation in a small temperature window between 200 and 300 K. Although the ΔT is mentioned as 10 K, the distance between the contacts is not specified. Still, if we assume the length of the sample (4 mm) as the probing distance, then the SSC at 200 K can be approximated as $15 \text{ nV}/(4 \text{ mm} \times 10 \text{K}) = 0.375 \,\mu\text{V/K} \text{ m}$ compared to 0.7 μ V/m obtained in this study. With further decrease in temperature below 180 K, the signal initially decreases and then goes through a local maximum around 120 K. Below 100 K there is again a gradual increase with decrease in T. Both SSC and SSR follow the same trend in the entire temperature window except at 30 K at which the



FIG. 4. T dependence of LSSE as SSR and SSC representations in Pt/LNMO/Au/GGG and fit to a power law. Inset shows a typical angular dependence at 170 K and corresponding fit to a sine function to extract the amplitude.

SSC is seen to drop in contrast to SSR. This nonmonotonic T dependence can result from a change in thermal magnon parameters like population, conductivity, and lifetime [20,65] or even effect of interface [66] and anisotropy [67]. However, in this study, we focus only on the monotonic decrease above 175 K that extends up to T_c . In analogy to previous reports, this region could be fitted to a $(T_c - T)^P$ power law [14,25,34,35]. The derived exponents are $P^{\text{SSR}} = 0.78 \pm 0.05$ and $P^{\text{SSC}} = 0.69 \pm 0.05$.

We perform a similar *T* dependence of LSSE in sample B to investigate the effect of crystallinity in determining the critical exponent. As expected, the $V_{\rm ISHE}$ displays a sinusoidal variation with in-plane field rotation (see Fig. 4 inset) in the entire *T* range, from which the amplitudes were extracted. We present the *T* dependence in Fig. 4 which manifests a similar trend and magnitude as sample A except at low *T*. Interestingly, we extract similar critical exponents, $P^{\rm SSR} = 0.78 \pm 0.04$ and $P^{\rm SSC} = 0.63 \pm 0.05$ by fitting the monotonic decrease in SSR above 170 K up to T_c (= 241 K). This suggests that the same physical mechanism determines spin transport near T_c for both samples irrespective of crystalline order.

IV. LSSE RESULTS ON EuO_{1-x}

In principle, the transverse thermal voltage could originate from pure magnon spin currents via LSSE as we observed in LNMO or from spin polarized charge currents via ANE [24,25,68]. In the case of electron doped EuO_{1-x} , there are available defect states in the band gap which allows electron conduction when the majority-states of the spin-split conduction band shift downward to overlap with the defect levels. Hence, generation of a transverse ANE voltage cannot be avoided when a vertical temperature gradient is applied. Accordingly, the ANE voltage is given by

$$V_{\rm ANE} = \theta_{\rm ANE} S \hat{\mathbf{m}} \times \Delta \mathbf{T}, \qquad (2)$$



FIG. 5. (a) Schematic illustration of the device geometry used for measuring ANE. (b) Variation of stack resistance with temperature for conducting EuO_{1-x} and insulating LNMO. Inset shows the peak in dR/dT for the conducting EuO_{1-x} at T_c of bulk EuO. (c) Calculated T dependence of resistivity of EuO_{1-x} considering a trilayer resistance model. (d) Measured ANE, ANE_{red} , and $(ANE_{red} + LSSE)$ voltage in EuO_{1-x} and $Pt(5 nm)/EuO_{1-x}$ at 25 K as a function of in-plane field angle for a constant power of 2 mW. The values are scaled as $(V_{TH} \times \text{heater area})/L$. (e) Field dependence of the thermal voltage in Pt/EuO_{1-x} for different applied power confirming the ferromagnetic origin of the signal. (f), (g) T dependence of the reduced ANE voltage for EuO_{1-x} (red triangles) and reduced ANE + LSSE for Pt/EuO_{1-x} (blue circles) in SSC and SSR units respectively. (h) LSSE voltages as SSC and SSR after separation of reduced ANE voltage from the total thermal voltage. Corresponding fits to power law and value of critical exponents are also indicated.

where V_{ANE} is the voltage produced by the ANE, θ_{ANE} is the anomalous Nernst angle, *S* is the Seebeck coefficient, $\hat{\mathbf{m}}$ is the unit vector along magnetization, and ΔT is a vector along the temperature gradient. Resistivity determination in bare EuO_{1-x} is tedious owing to the difficulty in getting proper ohmic contacts [69]. However, the conducting nature of our EuO_{1-x} films is evident from the *T* dependence of Pt/EuO_{1-x}/Pt trilayer resistance [see Fig. 5(b)] which shows a definite drop at the predicted metal-insulator transition temperature of EuO_{1-x}, corresponding to the T_c of bulk EuO [see inset of Fig. 5(b)] [44,45]. Hence, a proper analysis of LSSE requires an estimation of the ANE from bare EuO_{1-x}. LSSE + ANE, i.e., the total thermal signal (V_{TH}) in the Pt capped sample, we etch away the Pt, followed immediately by a protective coating of GE varnish. Then we study ANE in the same longitudinal configuration as shown in the schematic of Fig. 5(a). The angular variation of ANE with an in-plane applied field displays a similar sinusoidal variation as expected from Eq. (2), whose magnitude increases linearly with the applied heater power up to nearly 4 mW, as shown in Fig. 5(d)and the inset. In the same figure, the total thermal signal from a Pt capped EuO_{1-x} is also depicted. It is important to note that the ANE contribution in the total signal would be reduced due to the shunting of currents in the Pt layers, which we represent as ANE_{red}. An estimate of the reduction due to the top Pt layer can be done based on the approach by Bougiatioti *et al.* [68], who argued that in a NM/FM bilayer, ANE is reduced by a factor r/(1 + r), where r is the ratio of electrical conductance G of FM and NM. Consequently,

$$r = \frac{G_{\text{EuO}_{1-x}}}{G_{\text{Pt}}} = \frac{\rho_{\text{Pt}}}{\rho_{\text{EuO}_{1-x}}} \frac{t_{\text{EuO}_{1-x}}}{t_{\text{Pt}}}$$
(3)

with ρ the resistivity and *t* the thickness of the corresponding layer. The resistivity of EuO_{1-x} can be estimated to a fair degree from the measured trilayer resistance, by assuming a parallel connection of three resistances, corresponding to the two Pt layers and the EuO_{1-x} layer [see Fig. 5(e)]. Comparing to other reports on EuO_{1-x} [70], we find that this approach captures the main features of the *T*-dependent resistivity, particularly the MIT at *T*_{EuO}, reasonably well.

Substituting these values into Eq. (3) along with the measured thicknesses of EuO_{1-x} (97 nm) and Pt (5 nm) we get an estimated 99% reduction in ANE. Consequently, the thermal signal from the Pt capped sample is predominantly the LSSE signal. In addition, the ferromagnetic origin of the thermal signals could be confirmed from the field sweep results, as depicted in 5(e), where H is along $\alpha = 0$. Another parasitic voltage that is often associated with Pt is due to the induced ferromagnetism in Pt, in proximity to a FM. We rule out any significant contribution of this magnetic proximity effect (MPE) in our total thermal signal, based on the results of Bougiatioti et al. [68], who did not find any MPE in Pt when their FM resistivity was in the same order of magnitude as our EuO_{1-x} . Therefore, the pure LSSE signal can be extracted by simply subtracting the reduced ANE (ANE_{red}) from the total thermal signal generated from a Pt capped sample. Note that any LSSE contribution arising at the interface of EuO_{1-x} and bottom Pt layer will be of opposite sign (as the T gradient is reversed) and very negligible, due to the presence of thick insulating EuO_{1-x} in between.

The *T* dependence of ANE_{red} and LSSE + ANE_{red} is shown in Figs. 5(f) and 5(g) for both methods of scaling. An overall decrease in the signal is observed with an increase in *T*, which eventually reduces below the detection limit of our setup (~10 *nV*) above T_{EuO} of 65 K. We extend the same analysis as in LNMO to the pure LSSE signal shown in Fig. 5(h), by fitting the decay in LSSE signal to a power law of the form $(T_c - T)^P$. The derived exponents are $P^{SSR} =$ 1.24 ± 0.02 and $P^{SSC} = 1.06 \pm 0.06$. It is important to note that even though P^{SSC} is less than P^{SSR} , resembling the trend in LNMO, the values themselves are higher, arguably closer to 1. Now we qualitatively discuss the observed power-law dependence in LNMO and EuO_{1-x} in accordance with their *M*-*T* curve. The magnetization curve of LNMO was analyzed in the critical region by Lou *et al.* [71] using the Kouvel-Fisher method that yielded the critical exponent, $P = 0.408 \pm 0.011$. This value was in between those predicted by the mean-field model (=0.5) and the three-dimensional (3D) Heisenberg model (=0.365) [72]. A simple power*law fitting of our M(T) data on LNMO/STO also return a similar value of critical exponent, $P_{M(T)^{\text{LNMO}} = 0.39$ (see the Appendix). Taking the exponent as 0.408, we can now interpret our results based on the magnon-driven thermal spin pumping mechanism. Accordingly, the LSSE(*T*) should be proportional to $[(T_c - T)^{0.408}]^2 \sim (T_c - T)^{0.82}$. This is in close agreement with our derived exponents for $P_{\text{SSR}}^{\text{LNMO}} = 0.78$ in both epitaxial and polycrystalline films and slightly higher than $P_{\text{SSC}}^{\text{LNMO}}$.

Stoichiometric EuO is considered an ideal example of a 3D Heisenberg ferromagnet. However, oxygen vacancies in EuO is known to exert a strong influence on its magnetic interactions, thereby increasing the critical exponent to 0.48 [73]. Such an increment has also been observed for doped EuS [74]. The different interactions present in EuO_{1-x} makes the determination of critical exponents nontrivial and hence we adopt the reported value of 0.48 for comparison with our LSSE data. Conforming with our previous arguments, LSSE(*T*) should be proportional to $[(T_c - T)^{0.48}]^2 = (T_c - T)^{0.96}$ which matches quite closely with $P_{SSC}^{EuO_{1-x}} = 1.0$, albeit slightly less than $P_{SSC}^{EuO_{1-x}}$.

Now, the above agreement between the critical exponents of M(T) and LSSE assumes that the dominant *T*-dependent parameter in determining LSSE near T_c is G_{mix} . In a simplified picture, one can associate *T* dependence of G_{mix} solely to its real part, Re[G_{mix}], which can be approximated from the *T* dependence of SMR. Hence, in the next section, we investigate SMR for the polycrystalline LNMO sample.

V. SPIN HALL MAGNETORESISTANCE RESULTS

For SMR measurements we pattern the top Pt layer in sample B into a Hall bar of dimensions illustrated in Fig. 6(a). A small AC current $\leq 100 \ \mu$ A is applied at 333 Hz frequency and the generated transverse voltage (V_{trans}) in Pt is measured using a lock-in amplifier SR830 as a function of in-plane field angle. Here, we utilize transverse resistivity ρ_{xy} to characterize the SMR due to its low background signal and hence improved signal-to-noise ratio. **j** and **t** denote parallel and transverse to the current direction, whereas **n** is the out-of-plane direction. ρ_{xy} varies as a function of the magnetization orientation of LNMO, **m**, as [7]

$$\rho_{xy} = \rho_1 m_n + \rho_2 m_i m_t, \tag{4}$$

$$\rho_{xy} = \rho_2 \sin(\alpha) \cos(\alpha), \text{ for } m_n = 0, \tag{5}$$

where m_j , m_t , and m_n are projections of **m** onto the coordinate system, α is the orientation of applied field with respect to the transverse direction, and ρ_2 denotes magnitude of resistivity change due to SMR. Accordingly, Fig. 6(b) depicts



FIG. 6. (a) Schematic illustration of the device configuration used for measuring SMR. t, j, and n denote the coordinate axes along, transverse, and perpendicular to the current direction I_q , respectively. (b) In-plane angular variation of transverse resistance at 140- and 0.25-T field. Solid line is fit to $\sin(2\alpha)$ to determine SMR amplitude. (c) T dependence of normalized SMR and fit to Eq. (6) (solid line). (d) Calculated real part of spin mixing conductance at different T. Solid line depicts fit to a power law. Extracted critical exponent is also indicated.

a $\sin(2\alpha)$ variation of R_{xy} and its fit. Parasitic anisotropic magnetoresistance (AMR) contribution arising from conduction in LNMO or magnetic proximity effect (MPE) induced ferromagnetism in Pt is known to satisfy similar symmetry rules as SMR [75]. However, the high resistivity of LNMO compared to Pt prevents any significant current shunting and also avoids MPE induced effects [68]. Following the theoretical SMR model described by Chen *et al.* [7], the *T* dependence of SMR can be depicted using the following ratio:

$$\frac{\Delta\rho_{xy}}{\rho_{xy}} = \theta_{\rm sh}^2 \frac{\lambda_{\rm Pt}(T)}{t_{\rm Pt}} \frac{2\lambda_{\rm Pt}(T)G_r \tanh^2 \frac{t_{\rm Pt}}{2\lambda_{\rm Pt}(T)}}{\sigma_{\rm Pt}(T) + 2\lambda_{\rm Pt}(T)G_r \coth \frac{t_{\rm Pt}}{\lambda_{\rm Pt}(T)}}, \quad (6)$$

where θ_{sh} , t_{Pt} , $\lambda_{Pt}(T)$, and $\sigma_{Pt}(T)$ are the spin Hall angle, thickness, spin-diffusion length, and conductivity of Pt, respectively and G_r is real part of G_{mix} . We illustrate the Tdependence of SMR ratio in Fig. 6(c). Interestingly, the signal exhibits a peak around 50 K and vanishes above $T_c = 241$ K. This suggests that just like LSSE, SMR is also regulated by the long-range ferromagnetic correlations in the sample and is not affected by the short-range interactions that is known to exist in LNMO even above T_c [76].

The *T*-dependent parameters in the above equation have been extensively investigated by different groups. For instance Marmion *et al.* [77] ascribed the *T* dependence of SMR to variation in $\lambda_{Pt}(T)$, determined by the Elliot-Yafet mechanism for spin relaxation. θ_{sh} on the other hand is reported to change very weakly above 100 K and hence is often taken as constant [78]. We try fitting our SMR data based on Eq. (6), assuming a *T*-independent G_r and a $\theta_{sh} = 0.08$, only varying

TABLE I. List of samples and corresponding refined and adopted parameters.

	P ^{SSR}	P ^{SSC}	$P^{\rm SMR}$	T_c (K)	P_{M-T}
Sample A	0.78 ± 0.05	0.69 ± 0.05		241	0.41
Sample B	0.78 ± 0.04	0.63 ± 0.05	0.85 ± 0.15	241	0.41
EuO_{1-x}	1.24 ± 0.02	1.06 ± 0.06		65	0.48

 $\lambda_{\text{Pt}}(T)$ according to the Elliot-Yafet mechanism [$\lambda_{\text{Pt}}(T) = C/T$ in unit of nm]. However, as discussed by Wang *et al.* [14] for Pt/YIG, it fails to reproduce the high-*T* data [see fit in Fig. 6(c)]. Hence, we consider a *T*-dependent $G_r(T)$ which can be quantified by rearranging Eq. (6) as follows [14]:

$$G_r(T) = \frac{\sigma_{\rm Pt}(T)}{2\lambda_{\rm Pt}(T) \Big[\frac{\theta_{\rm sh}^2 \frac{\lambda_{\rm Pt}(T)}{t_{\rm Pt}} \tanh^2 \frac{t_{\rm Pt}}{2\lambda_{\rm Pt}(T)}}{\frac{\Delta_{\rm Px}}{\sigma_{\rm Y}} - \coth \frac{t_{\rm Pt}}{\lambda_{\rm Pt}(T)}\Big]}.$$
(7)

We consider $G_r(T)$ to be a function of T and backcalculate its values from our experimentally measured SMR results using Eq. (7), adopting $\theta_{sh} = 0.08$ and $\lambda_{Pt}(T) =$ $(2.6 \times 10^{-7})/T$ in unit of nm [14,77,78] (refined from the previous fit). We plot the calculated $G_r(T)$ and the power-law fit in Fig. 6(d). The important trait we observe is that the critical exponents conform very nearly to that of LSSE and also with the spin pumping mechanism outlined by Ohnuma et al. [37] (see Table I). It was speculated that previous investigations of critical exponents on YIG failed to come to a consensus with the theoretical predictions because of the ferrimagnetic nature of YIG, or other considerations like the magnetic surface anisotropy [38]. In this paper, both samples exhibit ferromagnetic interactions which allow direct comparison with the magnon-driven spin current model [12]. We also acknowledge that our choice of FM allows analysis adopting this simple picture, wherein we only consider T dependence of interfacial spin conductance and disregard other parameters such as the bulk spin conductance [79] and magnon chemical potential [80], which can also affect LSSE. Additionally, we could verify the interdependence of $G_r(T)$ and LSSE(T) without including the effective spin conductance G_s [81] in Eq. (6) suggesting negligible contribution from this term for LNMO. Incorporating these effects might better reproduce the behavior near T_c for other systems.

In LSSE, the signals are generated by magnon spin currents at the bulk of the material which travel to the interface and get pumped into the Pt layer. Hence both bulk and interface magnetization can affect the generated signals. In our experiments we observed that the power-law exponents of the SSE are related to the power-law exponent of the volume magnetization recorded using a standard SOUID magnetometer. Nature of M vs T and this correlation suggests that the interface magnetization contribution if present is identical to the bulk. Last, we can comment on the impact of scaling, namely SSR or SSC, on the derived exponents. We found a better correspondence between P^{SSR} and $P^{M_s^2}$ for LNMO and in contrast P^{SSC} conformed better with $P^{M_s^2}$ for EuO_{1-x}. This might suggest that at low T, when heat transport properties such as thermal conductivity and specific heat undergo large changes, SSC would be a better representation to incorporate those changes. However, near room temperature, SSR repre-



FIG. 7. (a) A double logarithmic plot of $T_c - T$ dependence of the magnetization for epitaxial LNMO. (b) M vs T at 100 Oe and its derivative for polycrystalline LNMO sample depicting the position of T_c . The GGG substrate contributes to the large paramagnetic background.

sentation overcomes uncertainties due to parasitic temperature drops across various interfaces, and hence might serve as a better choice. Alternately, one can also argue that Pt spin conversion parameters, especially $\lambda_{Pt}(T)$, which is known to increase appreciably only below 100 K, also affect the LSSE signal and hence need to be accounted for in the analysis. Simultaneous measurements of all *T*-dependent parameters at low *T* could be helpful in resolving this question.

VI. CONCLUSION

The T dependence of LSSE has been studied for three different Pt/FM hybrid structures across its ferromagnet to paramagnet transition temperature, namely Pt/LNMO/STO, Pt/LNMO/Au/GGG, and Pt/EuO_{1-x}/Pt/Si. Pure LSSE signal was obtained from the highly resistive LNMO whereas the LSSE had to be disentangled from the ANE signal generated in conducting EuO_{1-x} . A power-law behavior could describe the decay in LSSE approaching T_c for both LNMO and EuO_{1-x} , but the derived critical exponents were found to be characteristic of the material. We could interpret this power-law behavior based on the magnon-driven thermal spin pumping mechanism which suggests G_{mix} is the dominating parameter affecting LSSE and which in turn is proportional to M_s^2 . Additionally, we show this evaluation remains invariant despite varying the crystalline order in LNMO, but the method used for scaling LSSE becomes important, especially at low T. Finally, we confirm the correlation between magnetization and G_{mix} from SMR measurements on Pt/LNMO at different temperatures. Our work establishes the importance of G_{mix} in determining LSSE across ferromagnetic phase transition and also highlights the correlation between critical exponents of magnetic order parameter and thermal spin transport across NM/FM interfaces. Further systematic studies on different samples having different thicknesses and interface conditions are necessary to confirm whether the exponent is material specific or not. However, this correlation strongly suggests that for materials like LNMO and EuO_{1-x} , having simple magnetic structures, G_{mix} is the dominant parameter affecting LSSE. This serves as an important benchmark for future investigations.

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APPENDIX

In Fig. 7(a) we depict a simplified approach towards estimating the critical exponent of magnetization by fitting the M-T of epitaxial LNMO near T_c . It would have been ideal to compare the value of P obtained from M vs T and SSR, SSC vs T in the same temperature range very close to T_c , but

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the nature of the spin Seebeck experiments prevent this direct comparison. Ensuring that we operate in the linear region [as shown in Fig. 3(e)] and generate a minimum measurable signal of tens of nV (limited by the experimental setup), we are required to maintain a ΔT between 4 and 6 K near T_c . In addition, since the change in signal with temperature is not large, a minimum step size of 5 K was chosen to properly resolve the signals. These limitations meant that in the same temperature range as M vs T, we had only two spin Seebeck data points. Therefore, to incorporate more data points a larger range was taken. In Fig. 7(b), we highlight the position of the Curie temperature for the polycrystalline LNMO sample from the derivative of its M-T curve.

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